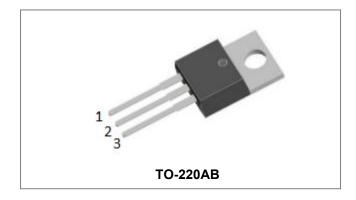


### MBR20100CTL

Technical Data Data Sheet N0758, Rev. A M



# MBR20100CTL SCHOTTKY RECTIFIER



### **Features**

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

**Circuit Diagram** 



### Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=100°C, rectangular wave form	10(Per Leg) 20(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>C</sub> = 25 °C	150	А

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 5A, Pulse, TJ = 25 °C @ 10A, Pulse, TJ = 25 °C	0.70 0.75	0.80 0.90	V
	V <sub>F2</sub>	@ 5A, Pulse, TJ = 125 °C @ 10A, Pulse, TJ = 125 °C	0.56 0.63	0.70 0.80	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = rated V_{R, T_J} = 25 \ ^{\circ}C$	0.006	1.0	mA
	I <sub>R2</sub>	$@V_R = rated V_R, T_J = 125 \circ C$	1	6.0	mA
Junction Capacitance(Per Leg)	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	230	250	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body		-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300  $\mu$ s, duty cycle < 2%

• China - Germany - Korea - Singapore - United States •

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## MBR20100CTL

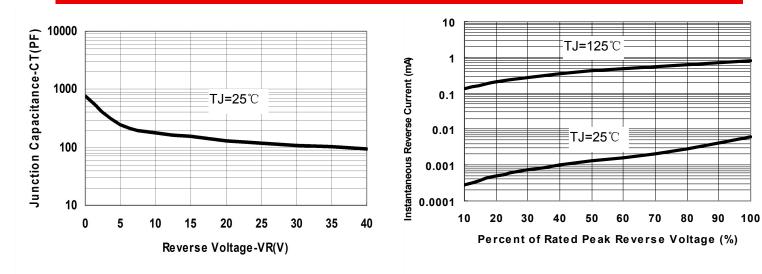
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RoHS 🔗

**Thermal-Mechanical Specifications:** 

**Ratings and Characteristics Curves** 

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g







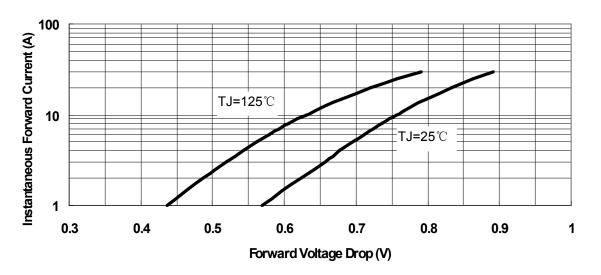


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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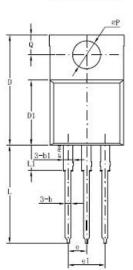
### **MBR20100CTL**

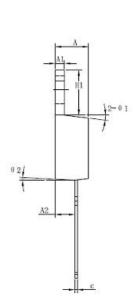


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### **Mechanical Dimensions TO-220AB**

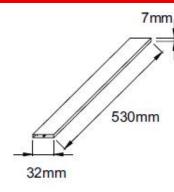






Symbol	Dimensions in millimeters			
-	Min	Typical	Мах	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		<b>4</b> °		

### **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

- MBR
- = Device Type = Forward Current (20A) = Reverse Voltage(100V)
  - = Configuration
  - = SSG

= Year = Week

20

100

CTL SSG

YΥ ww

L

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping	
MBR20100CTL	TO-220AB (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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